NSN 5961-00-481-4664

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-481-4664 **Inclosure Material:** Plastic **Overall Length:** Between 0.660 inches and 0.785 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.240 inches and 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector-to-emitter, substaining voltage, base open-circuited all transistor and 70.0 breakdown voltage, collector-to-emitter, base open all transistor and 70.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No